

**REMARKS**

The claims have been amended to recite the fabrication steps for fabricating a ferroelectric single crystal film structure for use, for example, in a microactuator and is directly based on the description in the Specification from page 5, line 20, to page 8, line 19, and is further supported in Figs. 2a and 2h of the subject Specification.

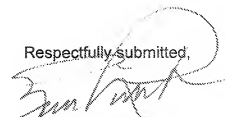
The method for preparing a ferroelectric single crystal as now specifically recited in claim 1 as amended, is not taught or suggested in any of the cited references alone or in combination, and is therefore believed to be patentable over the cited references under 35 USC 103.

The limitations of original claim 1 are now recited in new claim 14.

Claim 3, which depends from claim 1, has also been amended to specify the adhesive layer as being cured by heat treatment at the recited temperature. Claims 4-7, 9 and 12-13 are cancelled.

Reconsideration and allowance of claims 1-3, 8, 10-11 and 14 is respectfully solicited.

Respectfully submitted,

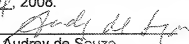
  
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Dated: November 13, 2008

**CERTIFICATE OF TRANSMISSION**

I hereby certify that this Preliminary Amendment w/RCE is being submitted to the U.S. Patent and Trademark Office via EFS Web to the Commissioner for Patents, P.O. Box 1450, Alexandria VA 22313-1450, on November 14, 2008.

By

  
Audrey de Souza